TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MZ157FK

Low Voltage Quad 2-Channel Multiplexer with 5 V Tolerant Inputs and Outputs

The TC7MZ157FK is a high performance CMOS multiplexer.

Designed for use in 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

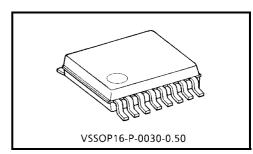
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for inputs.

It consists of four 2-input digital multiplexers with common select and strobe inputs.

When the strobe input (\overline{ST}) is held "H" level, selection of data is inhibited and all the outputs become "L" level.

The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.02 g (typ.)

Features

- Low voltage operation: $VCC = 2.0 \sim 3.6 \text{ V}$
- High speed operation: $t_{pd} = 5.8 \text{ ns (max)} (V_{CC} = 3.0 \sim 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Package: VSSOP16 (US16)
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 157 type.

000707EBA²

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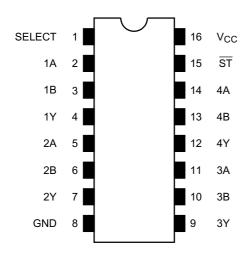
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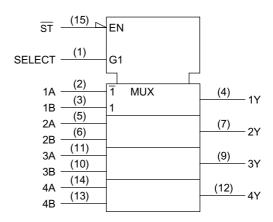
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Pin Assignment (top view)



IEC Logic Symbol



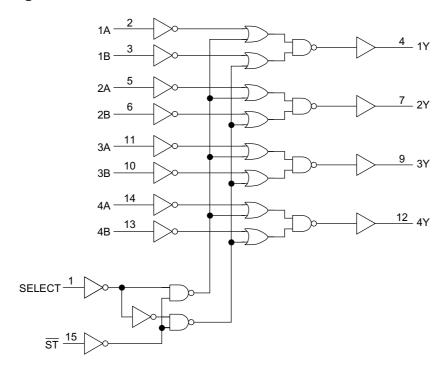
Truth Table

	Outputs					
ST	ST Select A B			Y		
Н	Х	Х	Х	L		
L	L	L	Х	L		
L	L	Н	X	Н		
L	Н	Х	L	L		
L	Н	Х	Н	Н		

X: Don't care



System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5~7.0	V	
DC input voltage	V _{IN}	-0.5~7.0	V	
DC output voltage	Vout	-0.5~7.0 (Note1)	V	
DC output voltage	٧٥٥١	-0.5~V _{CC} + 0.5 (Note2)	v	
Input diode current	I _{IK}	-50	mA	
Output diode current	I _{OK}	±50 (Note3)	mA	
DC output current	I _{OUT}	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature T _{stg} –6		-65~150	°C	

Note1: $V_{CC} = 0 V$

Note2: High or low state. IOUT absolute maximum rating must be observed.

Note3: $V_{OUT} < GND, V_{OUT} > V_{CC}$



Recommended Operating Conditions

Characteristics	Characteristics Symbol Rating		Unit	
Supply voltage	Voc	2.0~3.6	V	
Supply voltage	V _{CC}	1.5~3.6 (Note4)	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~5.5 (Note5)	V	
Output voltage		0~V _{CC} (Note6)	V	
Output current	I _{OH} /I _{OI}	±24 (Note7)	mA	
Output current	IOH/IOL	±12 (Note8)	ША	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note9)	ns/V	

Note4: Data retention only

Note5: $V_{CC} = 0 V$

Note6: High or low state Note7: $V_{CC} = 3.0 \sim 3.6 \text{ V}$ Note8: $V_{CC} = 2.7 \sim 3.0 \text{ V}$

Note9: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics ($Ta = -40 \sim 85$ °C)

Characteristics Symbol		Test Condition			Min	Max	Unit	
			rest condition		IVIIII	IVIAX	Offic	
Input voltage	High level	V _{IH}				2.0	_	V
iliput voltage	Low level	V _{IL}				_	0.8	v
Output voltage Low level			I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	_		
	High level	igh level V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 mA	2.7	2.2	_	V
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	
			$I_{OL} = 100 \mu A$	2.7~3.6	_	0.2		
	I ow level	Low level V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
	LOW level			$I_{OL} = 16 \text{ mA}$	3.0	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage current I _{IN}		V _{IN} = 0~5.5 V		2.7~3.6	_	±5.0	μΑ	
Power off leakage current I_{OFF} $V_{IN}/V_{OUT} = 5.5 V$		0	_	10.0	μΑ			
Quiescent supply current		Icc	$V_{IN} = V_{CC}$ or GND		2.7~3.6	—	10.0	
		100	V _{IN} = 3.6~5.5 V		2.7~3.6	—	±10.0	μΑ
Increase in I_{CC} per input ΔI_{CC}		Δl _{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6		500	



AC Characteristics ($Ta = -40 \sim 85$ °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	6.3	- ns
(A, B-Y)	t _{pHL}		3.3 ± 0.3	1.5	5.8	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	
(SELECT-Y)	t _{pHL}		3.3 ± 0.3	1.5	7.0	ns
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ns
(ST-Y)	t _{pHL}		3.3 ± 0.3	1.5	7.0	115
Output to output skew	t _{osLH}	(Note10)	2.7	_		ns
	t _{osHL}	(Note 10)	3.3 ± 0.3	_	1.0	20

Note10: This parameter is guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, Input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Output capacitance	C _{OUT}	_	0	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note1	3.3	25	pF

Note11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC

AC Test Circuit

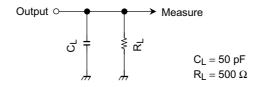


Figure 1

AC Waveform

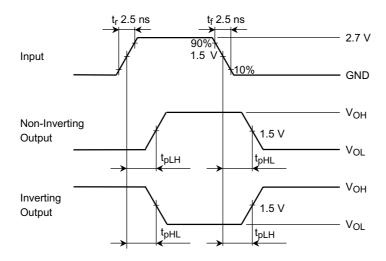
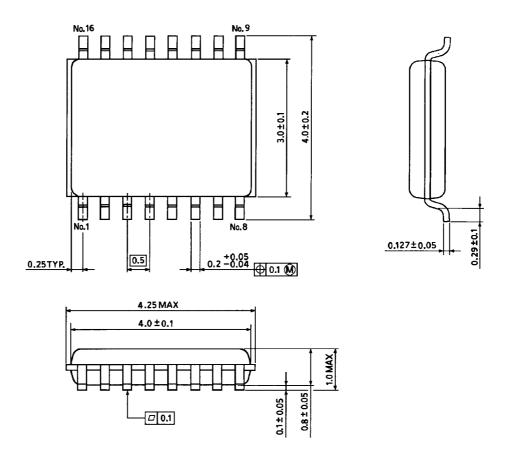


Figure 2 t_{pLH}, t_{pHL}

Package Dimensions



Weight: 0.02 g (typ.)